Complementary Power Transistors

DPAK For Surface Mount Applications

Designed for general purpose amplifier and low speed switching applications.

- · Lead Formed for Surface Mount Applications in Plastic Sleeves (No Suffix)
- Straight Lead Version in Plastic Sleeves ("-1" Suffix)
- Lead Formed Version in 16 mm Tape and Reel ("T4" Suffix)
- Electrically Similar to Popular TIP31 and TIP32 Series

MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Collector–Emitter Voltage	VCEO	100	Vdc
Collector–Base Voltage	VCB	100	Vdc
Emitter–Base Voltage	VEB	5	Vdc
Collector Current — Continuous Peak	IC	3 5	Adc
Base Current	ΙΒ	1	Adc
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D	15 0.12	Watts W/°C
Total Power Dissipation* @ T _A = 25°C Derate above 25°C	PD	1.56 0.012	Watts W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	8.3	°C/W
Thermal Resistance, Junction to Ambient*	$R_{\theta JA}$	80	°C/W
Lead Temperature for Soldering Purposes	TL	260	°C

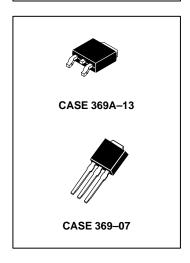
^{*} These ratings are applicable when surface mounted on the minimum pad size recommended.

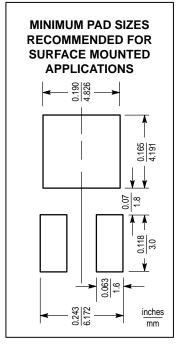
Preferred devices are Motorola recommended choices for future use and best overall value.

MJD31C PNP MJD32C

Motorola Preferred Devices

SILICON
POWER TRANSISTORS
3 AMPERES
100 VOLTS
15 WATTS







MJD31C MJD32C

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit		
OFF CHARACTERISTICS						
Collector–Emitter Sustaining Voltage (1) (IC = 30 mAdc, IB = 0)	VCEO(sus)	100	_	Vdc		
Collector Cutoff Current (V _{CE} = 60 Vdc, I _B = 0)	ICEO	_	50	μAdc		
Collector Cutoff Current (V _{CE} = Rated V _{CEO} , V _{EB} = 0)	ICES	_	20	μAdc		
Emitter Cutoff Current (VBE = 5 Vdc, IC = 0)	I _{EBO}	_	1	mAdc		
ON CHARACTERISTICS (1)						
DC Current Gain (I _C = 1 Adc, V _{CE} = 4 Vdc) (I _C = 3 Adc, V _{CE} = 4 Vdc)	hFE	25 10	— 50	_		
Collector–Emitter Saturation Voltage (I _C = 3 Adc, I _B = 375 mAdc)	VCE(sat)	_	1.2	Vdc		
Base–Emitter On Voltage (I _C = 3 Adc, V _{CE} = 4 Vdc)	V _{BE} (on)	_	1.8	Vdc		
DYNAMIC CHARACTERISTICS						
Current Gain — Bandwidth Product (2) (I _C = 500 mAdc, V _{CE} = 10 Vdc, f _{test} = 1 MHz)	fΤ	3	_	MHz		
Small–Signal Current Gain (I _C = 0.5 Adc, V _{CE} = 10 Vdc, f = 1 kHz)	h _{fe}	20		_		

⁽¹⁾ Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%. (2) $f_T = |h_{fe}| \bullet f_{test}$.

TYPICAL CHARACTERISTICS

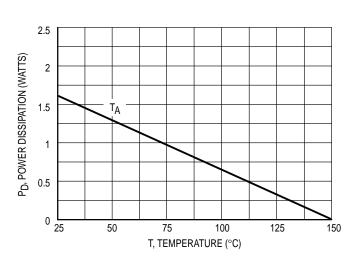
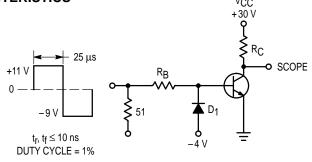


Figure 1. Power Derating



 R_B and R_C VARIED TO OBTAIN DESIRED CURRENT LEVELS D1 MUST BE FAST RECOVERY TYPE, e.g.: 1N5825 USED ABOVE $I_B\approx 100$ mA MSD6100 USED BELOW $I_B\approx 100$ mA REVERSE ALL POLARITIES FOR PNP.

Figure 2. Switching Time Test Circuit

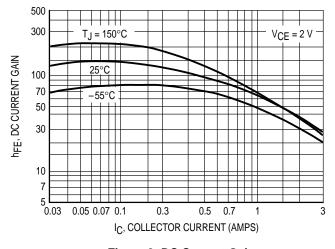


Figure 3. DC Current Gain

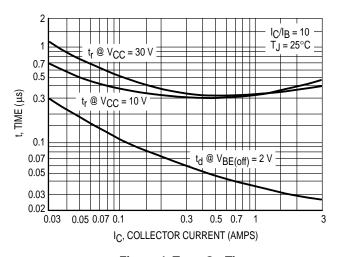


Figure 4. Turn-On Time

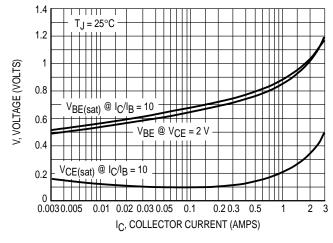


Figure 5. "On" Voltages

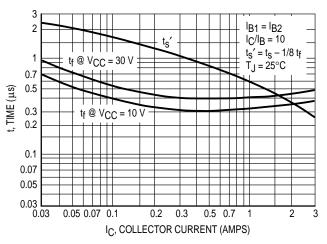
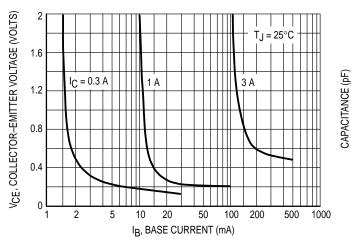


Figure 6. Turn-Off Time

MJD31C MJD32C



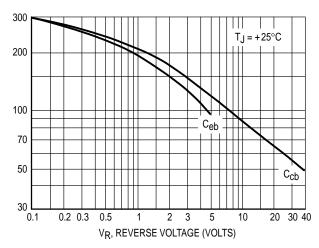


Figure 7. Collector Saturation Region

Figure 8. Capacitance

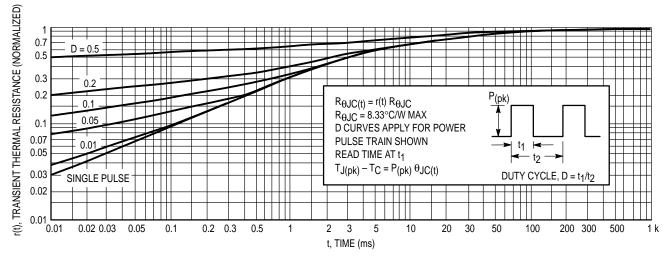


Figure 9. Thermal Response

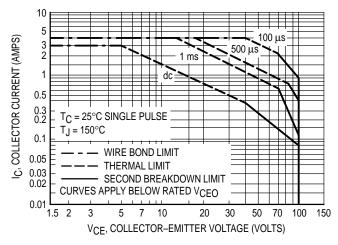
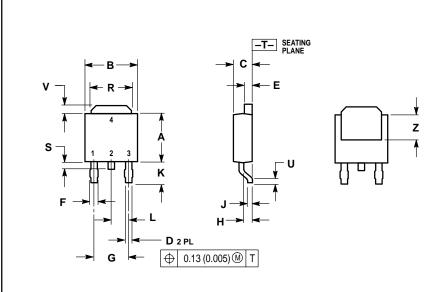


Figure 10. Active Region Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_{\text{C}} - V_{\text{CE}}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 10 is based on $T_{J(pk)} = 150^{\circ}C$; T_{C} is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \le 150^{\circ}C$. $T_{J(pk)}$ may be calculated from the data in Figure 9. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

PACKAGE DIMENSIONS



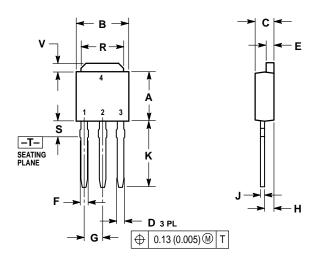
- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.235	0.250	5.97	6.35
В	0.250	0.265	6.35	6.73
С	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
Е	0.033	0.040	0.84	1.01
F	0.037	0.047	0.94	1.19
G	0.180 BSC		4.58 BSC	
Н	0.034	0.040	0.87	1.01
ſ	0.018	0.023	0.46	0.58
K	0.102	0.114	2.60	2.89
٦	0.090 BSC		2.29 BSC	
R	0.175	0.215	4.45	5.46
S	0.020	0.050	0.51	1.27
U	0.020		0.51	
٧	0.030	0.050	0.77	1.27
Z	0.138		3.51	

STYLE 1: PIN 1. BASE

- 2. COLLECTOR
 3. EMITTER
 4. COLLECTOR

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- NOTES:
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J	0.018	0.023	0.46	0.58
K	0.350	0.380	8.89	9.65
R	0.175	0.215	4.45	5.46
S	0.050	0.090	1.27	2.28
٧	0.030	0.050	0.77	1.27

- STYLE 1: PIN 1. BASE

 - 2. COLLECTOR
 3. EMITTER
 4. COLLECTOR

CASE 369-07 ISSUE K

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